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Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

MAX4983E/MAX4984E

General Description

The MAX4983E/MAX4984E are high ESD-protected analog switches that combine the low on-capacitance and low on-resistance necessary for high-performance switching applications. COM1 and COM2 are protected against $\pm 15\text{kV}$ ESD without latchup or damage. The devices are ideal for USB 2.0 Hi-Speed applications at 480Mbps. The switches also handle all the requirements for USB low- and full-speed signaling.

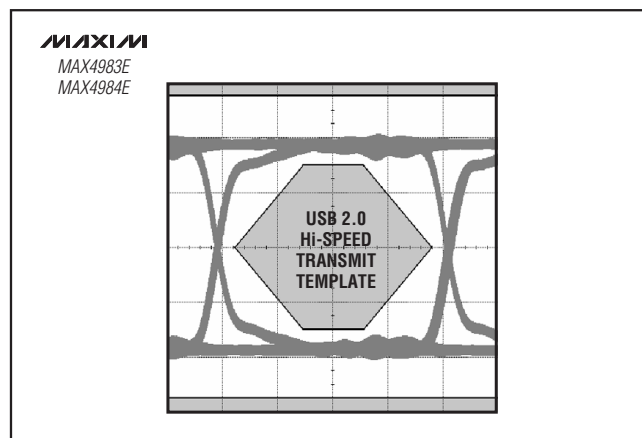
The MAX4983E/MAX4984E double-pole/double-throw (DPDT) switches are fully specified to operate from a single +2.8V to +5.5V power supply and are protected against a +5.5V short to COM1 and COM2. This feature makes the MAX4983E/MAX4984E fully compliant with the USB 2.0 specification of VBUS fault protection. The devices feature low-threshold-voltage logic inputs, permitting them to be used with low I/O voltage systems. The MAX4983E features an active-low enable input ($\overline{\text{EN}}$) that when driven high sets the device in shutdown mode. The MAX4984E features an active-high enable input (EN) that when driven low sets the device in shutdown mode. When the device is in shutdown mode, the quiescent supply current is reduced to 0.1 μA .

The MAX4983E/MAX4984E are available in a space-saving, 10-pin, 1.4mm x 1.8mm UTQFN package, and operate over a -40°C to $+85^{\circ}\text{C}$ temperature range.

Applications

Cell Phones	Notebook Computers
PDA's	Video Switching
Digital Still Cameras	Bus Switches
GPS	

Eye Diagram



Features

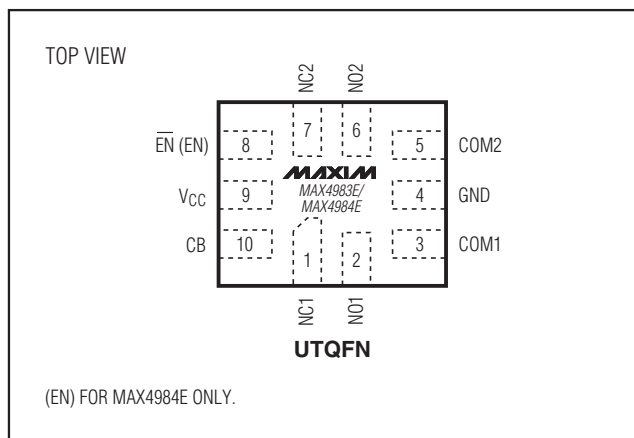
- ◆ USB Hi-Speed Switching
- ◆ ESD Protection on COM
 - $\pm 15\text{kV}$ Human Body Model
 - $\pm 15\text{kV}$ IEC 61000-4-2 Air Gap
 - $\pm 8\text{kV}$ IEC 61000-4-2 Contact
- ◆ Power-Supply Range: +2.8V to +5.5V
- ◆ Low 5 Ω (typ) On-Resistance (R_{ON})
- ◆ -3dB Bandwidth: 950MHz (typ)
- ◆ Compatible with Logic I/O Down to 1.4V
- ◆ COM Analog Inputs Fault Protected Against Shorts to +5.5V
- ◆ Low Supply Current 0.6 μA (typ)
- ◆ Enable Input:
 - Active-Low ($\overline{\text{EN}}$) MAX4983E
 - Active-High (EN) MAX4984E
- ◆ Small 10-Pin, 1.4mm x 1.8mm UTQFN

Ordering Information

PART	PIN-PACKAGE	TOP MARK
MAX4983EEVB+	10 Ultra-Thin QFN	AAA
MAX4984EEVB+	10 Ultra-Thin QFN	AAB

Note: All devices operate over the -40°C to $+85^{\circ}\text{C}$ extended temperature range.
+Denotes a lead-free package.

Pin Configuration



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ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND.)

V_{CC} , COM₋, NO₋, NC₋, EN, $\overline{\text{EN}}$, CB -0.3V to +6.0V

Continuous Current into Any Terminal $\pm 30\text{mA}$

Continuous Power Dissipation ($T_A = +70^\circ\text{C}$)

10-Pin UTQFN (derate $6.9\text{mW}/^\circ\text{C}$ above $+70^\circ\text{C}$) 559mW

Junction-to-Case Thermal Resistance (θ_{JC}) (Note 1)

10-Pin UTQFN $20.1^\circ\text{C}/\text{W}$

Junction-to-Ambient Thermal Resistance (θ_{JA}) (Note 1)

10-Pin UTQFN $143.1^\circ\text{C}/\text{W}$

Operating Temperature Range -40°C to $+85^\circ\text{C}$

Junction Temperature Range $+150^\circ\text{C}$

Storage Temperature Range -65°C to $+150^\circ\text{C}$

Lead Temperature (soldering 10s) $+300^\circ\text{C}$

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

($V_{CC} = +2.8\text{V}$ to $+5.5\text{V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise noted. Typical values are at $V_{CC} = +3.0\text{V}$, $T_A = +25^\circ\text{C}$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Power-Supply Range	V_{CC}		2.8		5.5	V
Supply Current	I_{CC}	$V_{CB} = 0\text{V}$ or V_{CC} , $\overline{V_{EN}} = 0\text{V}$ or $V_{EN} = V_{CC}$	$V_{CC} = 3.0\text{V}$	0.6	1.5	μA
			$V_{CC} = 5.5\text{V}$	3	6.5	
Shutdown Supply Current	I_{SHDN}	Switch disabled ($\overline{V_{EN}} = V_{CC}$ or $V_{EN} = 0\text{V}$)		0.1		μA
Increase in Supply Current with V_{CB} , V_{EN} Voltage		$0 \leq V_{CB} \leq V_{IL}$ or $V_{IH} \leq V_{CB} \leq V_{CC}$ or $0 \leq V_{EN} \leq V_{IL}$ or $V_{IH} \leq V_{EN} \leq V_{CC}$			2	μA
Analog Signal Range	V_{COM} , V_{NO} , V_{NC}	$V_{EN} = V_{CC}$ or $\overline{V_{EN}} = 0\text{V}$ (Note 3)	0		V_{CC}	V
Fault-Protection Trip Threshold	V_{FP}	COM ₋ only, $T_A = +25^\circ\text{C}$	$V_{CC} + 0.6$	$V_{CC} + 0.8$	$V_{CC} + 1$	V
On-Resistance	R_{ON}	$V_{COM} = 0\text{V}$ to V_{CC}		5	10	Ω
		$V_{COM} = 3.6\text{V}$, $V_{CC} = 3.0\text{V}$		5.5		
On-Resistance Match Between Channels	ΔR_{ON}	$V_{CC} = 3.0\text{V}$, $V_{COM} = 2\text{V}$ (Note 4)		0.1	1	Ω
On-Resistance Flatness	R_{FLAT}	$V_{CC} = 3.0\text{V}$, $V_{COM} = 0\text{V}$ to V_{CC} (Note 5)		0.1		Ω
Off-Leakage Current	$I_{COM(OFF)}$	$V_{CC} = 4.5\text{V}$, $V_{COM} = 0\text{V}$ or 4.5V , V_{NO} , $V_{NC} = 4.5\text{V}$ or 0V	-250		+250	nA
		$V_{CC} = 5.5\text{V}$, $V_{COM} = 0\text{V}$ or 5.5V , V_{NO} , V_{NC} with $50\mu\text{A}$ sink current to GND			180	μA
On-Leakage Current	$I_{COM(ON)}$	$V_{CC} = 5.5\text{V}$, $V_{COM} = 0\text{V}$ or 5.5V , V_{NO} , $V_{NC} = \text{unconnected}$	-250		+250	nA
AC PERFORMANCE						
On-Channel -3dB Bandwidth	BW	$R_L = R_S = 50\Omega$, signal = 0dBm		950		MHz
Off-Isolation	V_{ISO}	V_{NO} , $V_{NC} = 0\text{dBm}$, $R_L = R_S = 50\Omega$ (Figure 1)	$f = 10\text{MHz}$	-48		dB
			$f = 250\text{MHz}$	-20		
			$f = 500\text{MHz}$	-17		

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

MAX4983E/MAX4984E

ELECTRICAL CHARACTERISTICS (continued)

($V_{CC} = +2.8\text{V}$ to $+5.5\text{V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise noted. Typical values are at $V_{CC} = +3.0\text{V}$, $T_A = +25^\circ\text{C}$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Crosstalk (Note 6)	V _{CT}	V _{NO} , V _{NC} = 0dBm, R _L = R _S = 50Ω, Figure 1	f = 10MHz	-73		dB	
			f = 250MHz	-54			
			f = 500MHz	-33			
LOGIC INPUT							
Input Logic-High	V _{IH}			1.4			V
Input Logic-Low	V _{IL}				0.5		V
Input Leakage Current	I _{IN}			-250	+250		nA
DYNAMIC							
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 1.5V, R _L = 300Ω, C _L = 35pF, V _{EN} = V _{CC} to 0V or V _{EN} = 0V to V _{CC} (Figure 2)		20	100		μs
Turn-Off Time	t _{OFF}	V _{NO} or V _{NC} = 1.5V, R _L = 300Ω, C _L = 35pF, V _{EN} = V _{CC} to 0V or V _{EN} = 0V to V _{CC} (Figure 2)		1	5		μs
Propagation Delay	t _{PLH} , t _{PHL}	R _L = R _S = 50Ω, Figure 3		100			ps
Fault Protection Response Time	t _{FP}	V _{COM} = 0V to 5V step, R _L = R _S = 50Ω, V _{CC} = 3.3V (Figure 4)		0.5	5.0		μs
Fault Protection Recovery Time	t _{FPR}	V _{COM} = 5V to 0V step, R _L = R _S = 50Ω, V _{CC} = 3.3V (Figure 4)		100			μs
Output Skew Between Switches	t _{SK}	Skew between switch 1 and 2, R _L = R _S = 50Ω, (Figure 3, Note 7)		40			ps
NO_ or NC_ Off-Capacitance	C _{NO(OFF)} or C _{NC(OFF)}	f = 1MHz (Figure 5, Note 7)		2			pF
COM Off-Capacitance (Figure 5, Note 7)	C _{COM(OFF)}	f = 1MHz		5.5		pF	
		f = 240MHz		4.8			
COM On-Capacitance (Figure 5, Note 7)	C _{COM(ON)}	f = 1MHz		6.5		pF	
		f = 240MHz		5.5			
Total Harmonic Distortion Plus Noise	THD+N	V _{COM} = 1V _{P-P} , V _{BIAS} = 1V, R _L = R _S = 50Ω, f = 20Hz to 20kHz		0.03			%
ESD PROTECTION							
COM1, COM2		Human Body Model		±15		kV	
		IEC 61000-4-2 Air-Gap Discharge		±15			
		IEC 61000-4-2 Contact Discharge		±8			
All Pins		Human Body Model		±2			

Note 2: All devices are 100% production tested at $T_A = +25^\circ\text{C}$. All temperature limits are guaranteed by design.

Note 3: The switch turns off for voltages above V_{FP} , protecting downstream circuits in case of a fault condition.

Note 4: $\Delta R_{ON(MAX)} = \text{ABS}(R_{ON(CH1)} - R_{ON(CH2)})$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance, as measured over specified analog signal ranges.

Note 6: Between any two switches.

Note 7: Switch off-capacitance, switch on-capacitance, and output skew between switches are not production tested; guaranteed by design.

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

Test Circuits/Timing Diagrams

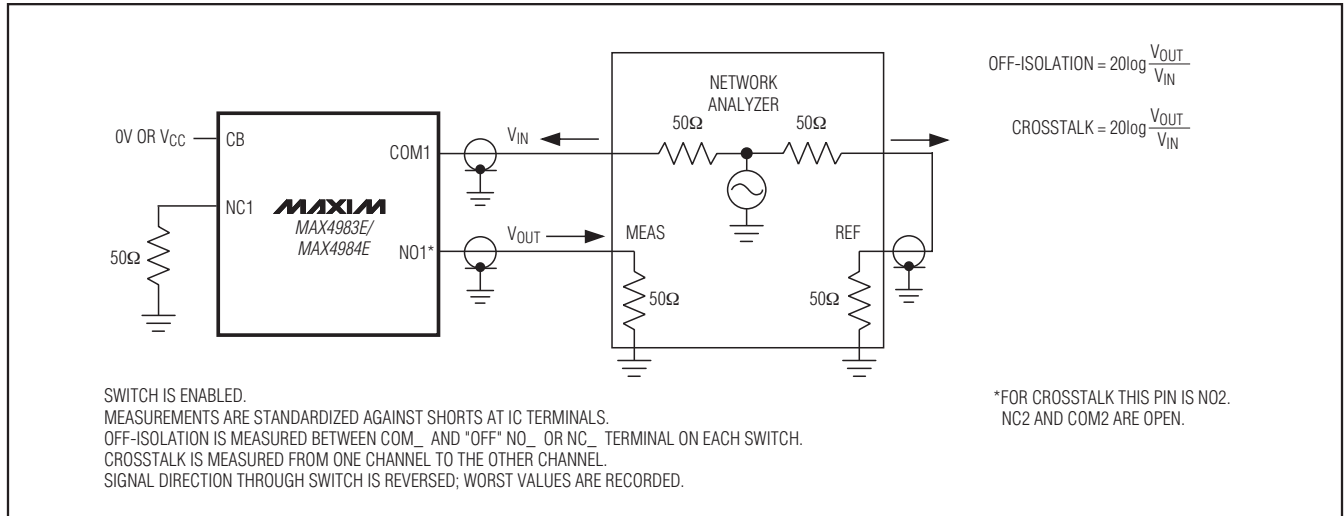


Figure 1. Off-Isolation and Crosstalk

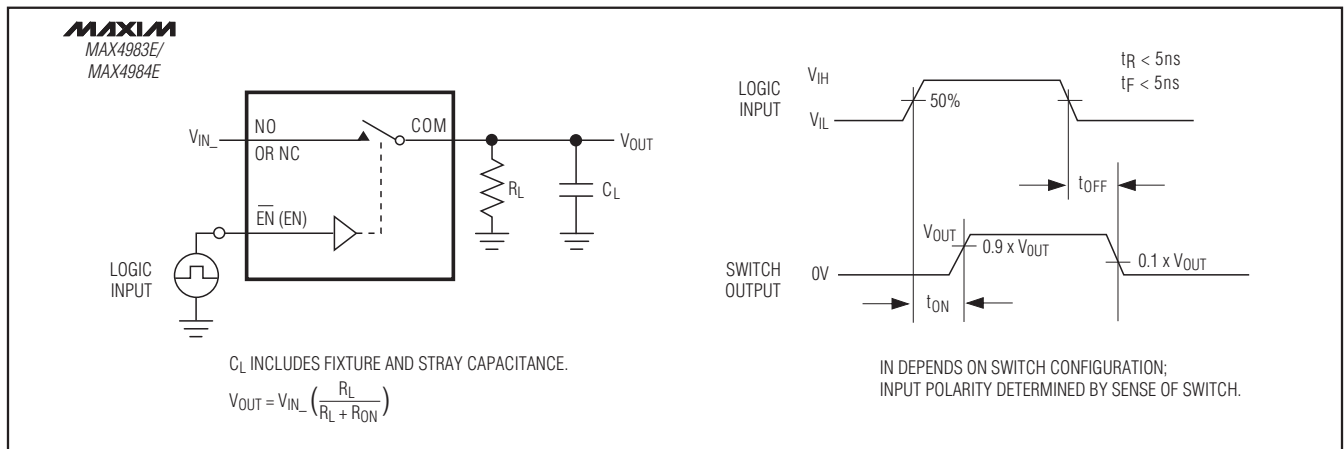


Figure 2. Switching Time

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Test Circuits/Timing Diagrams (continued)

MAX4983E/MAX4984E

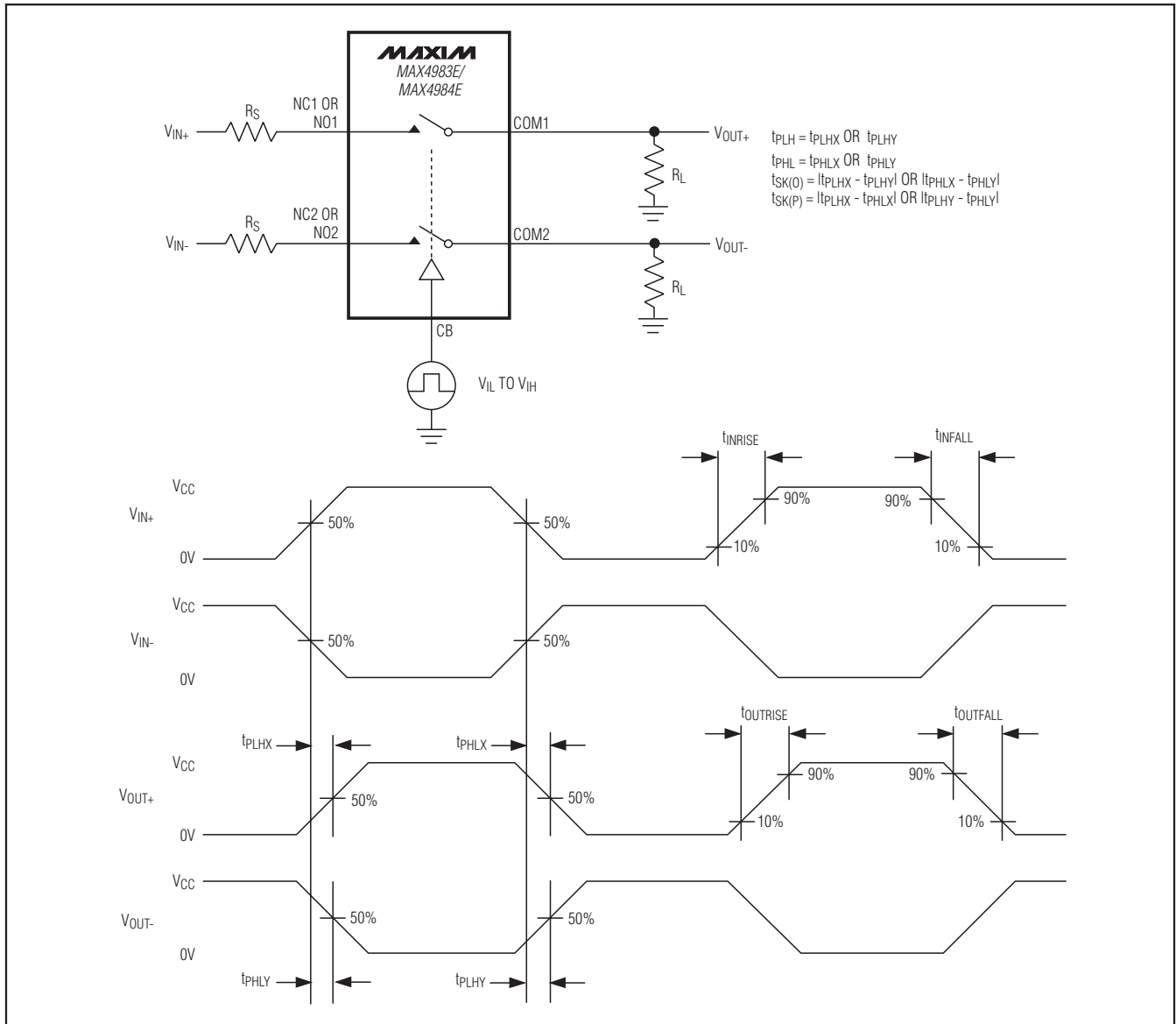


Figure 3. Output Signal Skew, Rise/Fall Time, Propagation Delay

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

Test Circuits/Timing Diagrams (continued)

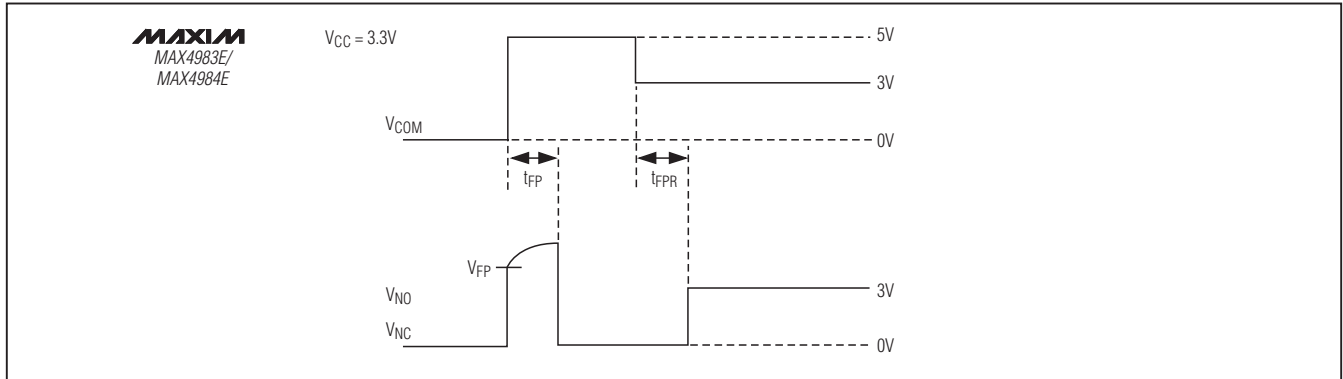


Figure 4. Fault-Protection Response/Recovery Time

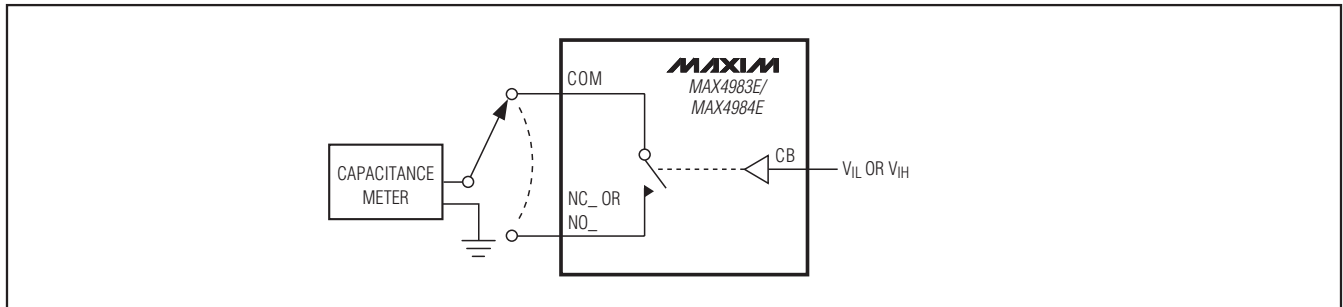


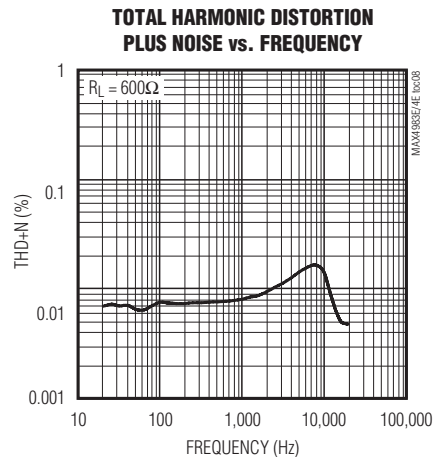
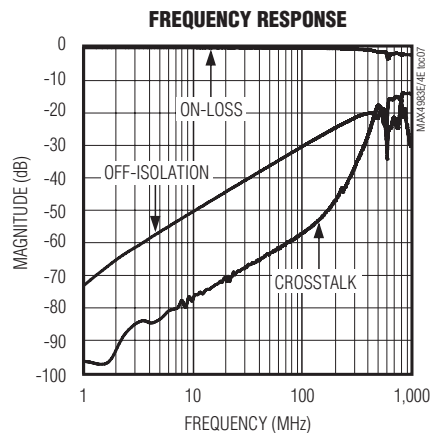
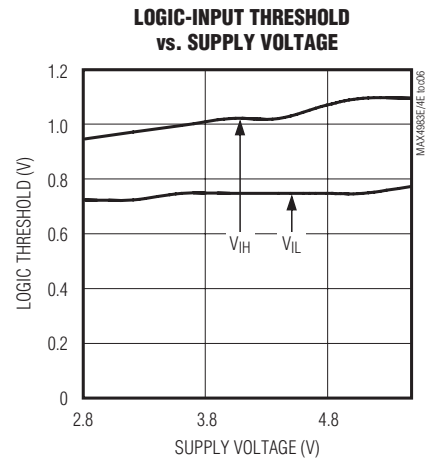
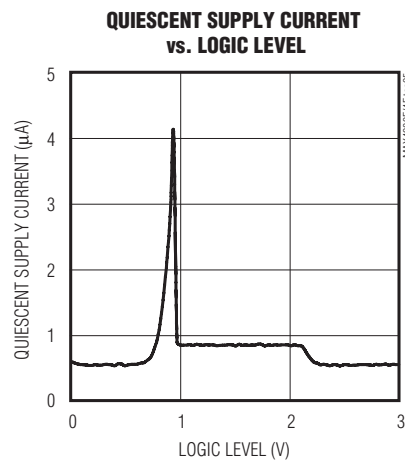
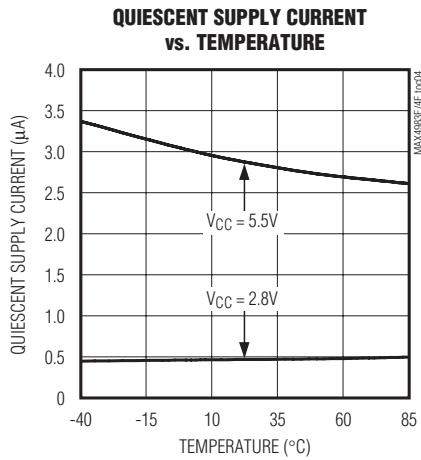
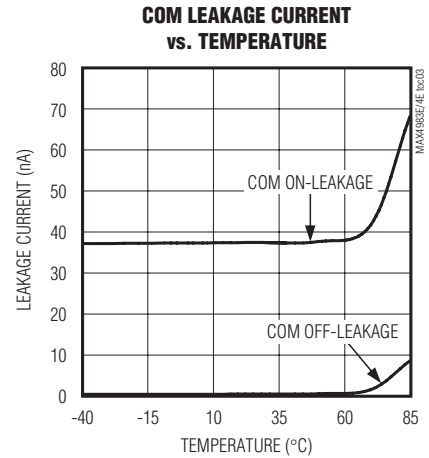
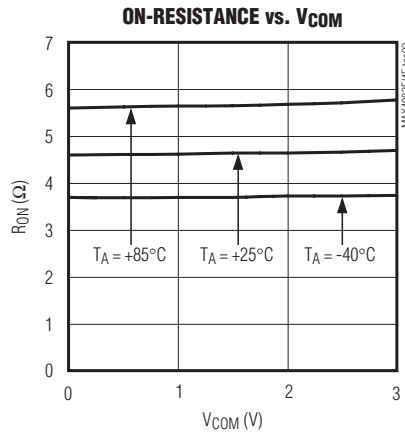
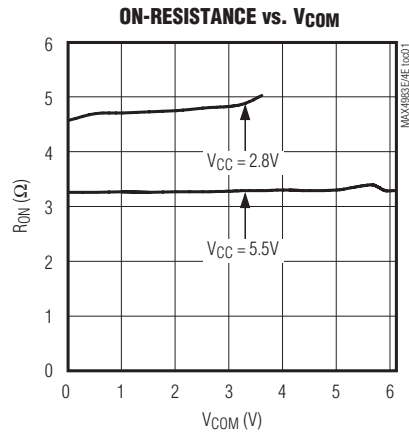
Figure 5. Channel Off-/On-Capacitance

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Typical Operating Characteristics

($V_{CC} = 3.0\text{V}$, $T_A = +25^\circ\text{C}$, unless otherwise noted.)

MAX4983E/MAX4984E



Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

Pin Description

PIN		NAME	FUNCTION
MAX4983E	MAX4984E		
1	1	NC1	Normally Closed Terminal for Switch 1
2	2	NO1	Normally Open Terminal for Switch 1
3	3	COM1	Common Terminal for Switch 1
4	4	GND	Ground
5	5	COM2	Common Terminal for Switch 2
6	6	NO2	Normally Open Terminal for Switch 2
7	7	NC2	Normally Closed Terminal for Switch 2
8	—	$\overline{\text{EN}}$	Active-Low Enable Input. Drive $\overline{\text{EN}}$ high to put switches in high impedance. Drive $\overline{\text{EN}}$ low for normal operation.
—	8	EN	Active-High Enable Input. Drive EN low to put switches in high impedance. Drive EN high for normal operation.
9	9	V _{CC}	Positive Supply Voltage Input. Bypass V _{CC} to GND with a 0.1 μF ceramic capacitor as close as possible to the device.
10	10	CB	Digital Control Input. Drive CB low to connect COM ₊ to NC ₊ . Drive CB high to connect COM ₊ to NO ₊ .

Detailed Description

The MAX4983E/MAX4984E are $\pm 15\text{kV}$ ESD-protected DPDT analog switches. The devices are ideal for USB 2.0 Hi-Speed (480Mbps) switching applications and also meet USB low- and full-speed requirements.

The MAX4983E/MAX4984E are fully specified to operate from a single +2.8V to +5.5V supply. The low V_{IH} threshold of the devices permits them to be used with logic levels as low as 1.4V. The MAX4983E/MAX4984E are based on a charge-pump-assisted n-channel architecture. The devices feature a shutdown mode to reduce the quiescent current to less than 0.1 μA (typ).

Digital Control Input

The MAX4983E/MAX4984E provide a single-bit control logic input, CB. CB controls the position of the switches as shown in the *Functional Diagram/Truth Table*. Driving CB rail-to-rail minimizes power consumption. With a +2.8V to +5.5V supply voltage range, the device is +1.4V logic compatible.

Analog Signal Levels

The on-resistance of the MAX4983E/MAX4984E is very low and stable as the analog input signals are swept from ground to V_{CC} (see the *Typical Operating Characteristics*). These switches are bidirectional, allowing NO₊, NC₊, and COM₊ to be configured as either inputs or

outputs. The charge-pump-assisted n-channel architecture allows the switch to pass analog signals that exceed V_{CC} up to the overvoltage fault protection threshold. This allows USB signals that exceed V_{CC} to pass, allowing compliance with USB requirements for voltage levels.

Overvoltage Fault Protection

The MAX4983E/MAX4984E feature overvoltage fault protection on COM₊. Fault protection protects the switch and USB transceiver from damaging voltage levels. When voltages on COM exceed the fault protection threshold, (V_{FP}), COM₊, NC₊ and NO₊ are high impedance.

Enable Input

The MAX4983E/MAX4984E feature a shutdown mode that reduces the supply current to less than 0.1 μA and places COM₊ in high impedance. Drive $\overline{\text{EN}}$ high for the MAX4983E or EN low for the MAX4984E to place the devices in shutdown mode. When $\overline{\text{EN}}$ is driven low or EN is driven high, the devices are in normal operation.

Applications Information

USB Switching

The MAX4983E/MAX4984E analog switches are fully compliant with the USB 2.0 specification. The low on-resistance and low on-capacitance of these switches make them ideal for high-performance switching applications.

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The MAX4983E/MAX4984E are ideal for routing USB data lines (see Figure 6) and for applications that require switching between multiple USB hosts (see Figure 7). The MAX4983E/MAX4984E also feature overvoltage fault protection to guard systems against shorts to the USB VBUS voltage that is required for all USB applications.

Extended ESD Protection

As with all Maxim devices, ESD-protection structures are incorporated on all pins to protect against electrostatic discharges encountered during handling and assembly. COM1 and COM2 are further protected against static electricity. The ESD structures withstand high ESD in normal operation and when the device is powered down. After an ESD event, the MAX4983E/MAX4984E continue to function without latchup.

The MAX4983E and MAX4984E are characterized for protection to the following limits:

- $\pm 15\text{kV}$ using Human Body Model
- $\pm 8\text{kV}$ using IEC 61000-4-2 Contact Discharge method
- $\pm 15\text{kV}$ using IEC 61000-4-2 Air-Gap Discharge method

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 8a shows the Human Body Model and Figure 8b shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a 1.5k Ω resistor.

IEC 61000-4-2

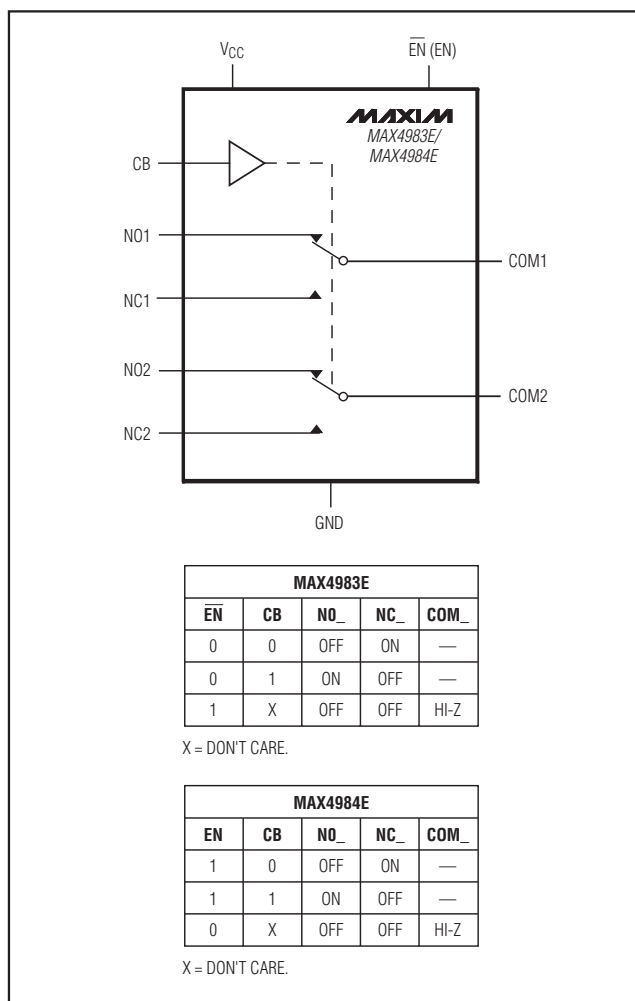
The main difference between tests done using the Human Body Model and IEC 61000-4-2 is higher peak current in IEC 61000-4-2. Because series resistance is lower in the IEC 61000-4-2 ESD test model (Figure 9a), the ESD-withstand voltage measured to this standard is generally lower than that measured using the Human Body Model. Figure 9b shows the current waveform for the $\pm 8\text{kV}$ IEC 61000-4-2 Level 4 ESD Contact Discharge test.

The Air-Gap Discharge test involves approaching the device with a charged probe. The Contact Discharge method connects the probe to the device before the probe is energized.

Layout

USB Hi-Speed requires careful PCB layout with 45 Ω controlled-impedance matched traces of equal lengths.

Functional Diagram/Truth Table



Ensure that bypass capacitors are as close as possible to the device. Use large ground planes where possible.

Power-Supply Sequencing

Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device.

Proper power-supply sequencing is recommended for all devices. Always apply VCC before applying analog signals, especially if the analog signal is not current limited.

Chip Information

PROCESS: BiCMOS

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

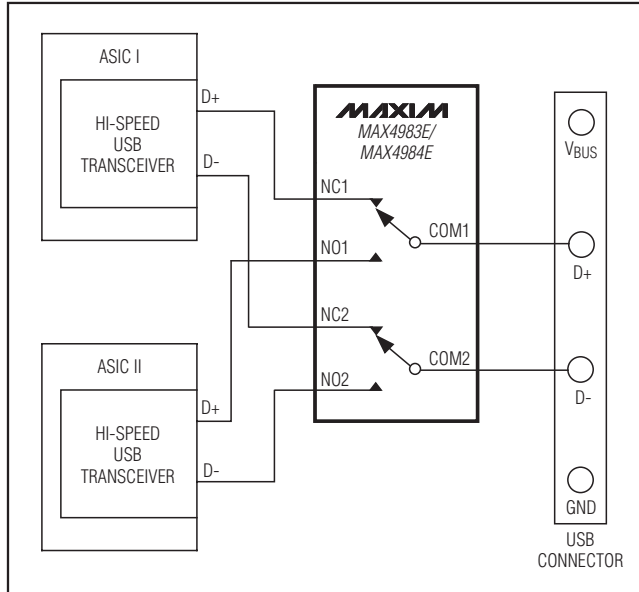


Figure 6. USB Data Routing/Typical Application Circuit

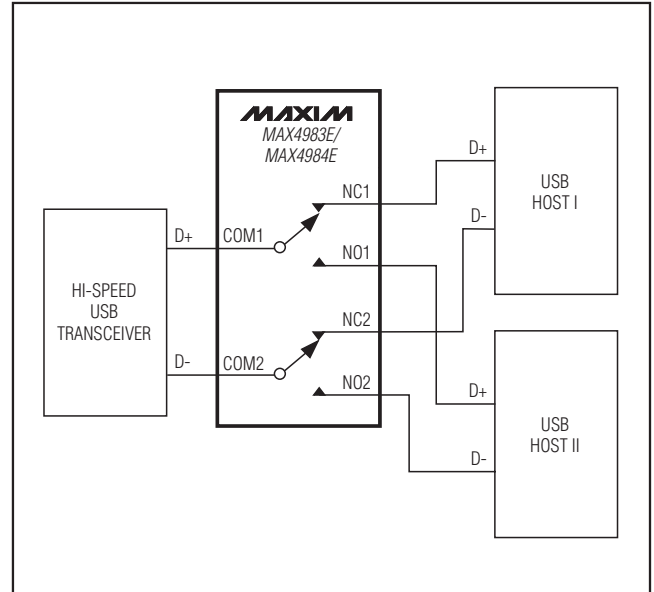


Figure 7. Switching Between Multiple USB Hosts

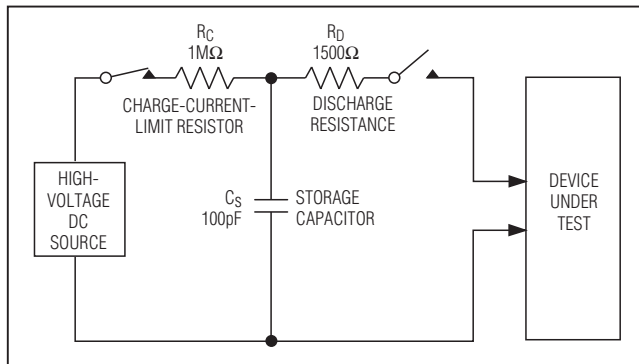


Figure 8a. Human Body ESD Test Model

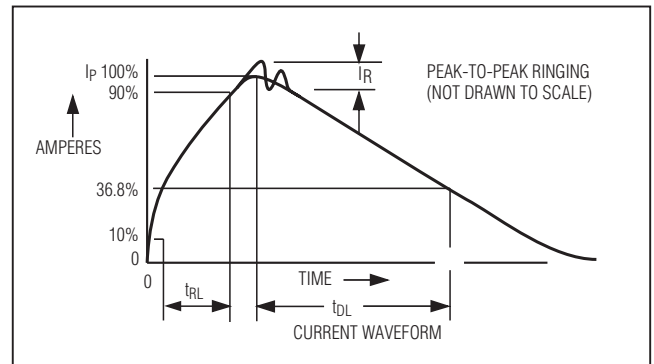


Figure 8b. Human Body Current Waveform

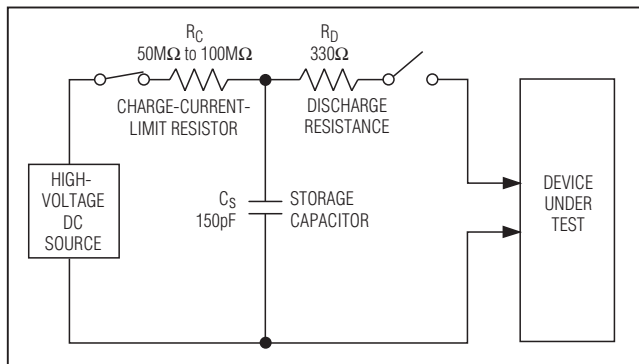


Figure 9a. IEC 61000-4-2 ESD Test Model

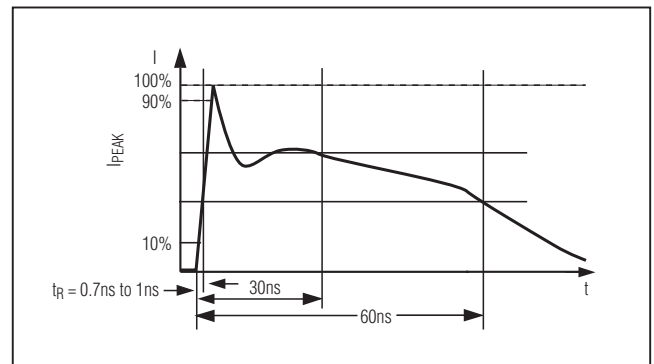


Figure 9b. IEC 61000-4-2 ESD Generator Current Waveform

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

Package Information

For the latest package outline information, go to www.maxim-ic.com/packages.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
10 Ultra-Thin QFN	V101A1CN-1	21-0028

MAX4983E/MAX4984E

Hi-Speed USB 2.0 Switches with $\pm 15\text{kV}$ ESD

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	2/08	Initial release	—
1	5/08	Removal of future product asterisks, global change to Hi-Speed	1, 8, 9, 10
2	9/08	Changes to EC table	3

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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